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SEMICONDUCTOR®

November 2013

FQPF27N25

N-Channel QFET[®] MOSFET 250 V, 14 A, 110 m Ω

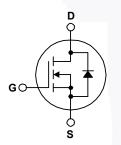
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

Features

- 14 A, 250 V, $R_{DS(on)}$ = 110 m Ω (Max.) @ V_{GS} = 10 V, I_D = 7 A
- Low Gate Charge (Typ. 50 nC)
- Low Crss (Typ. 45 pF)
- 100% Avalanche Tested





Absolute Maximum Ratings T_c = 25°C unless otherwise noted.

Symbol	Parameter		FQPF27N25	Unit
V _{DSS}	Drain-Source Voltage		250	V
I _D	Drain Current - Continuous (T _C = 25°C	C)	14	A
	- Continuous (T _C = 100°	°C)	8.9	A
I _{DM}	Drain Current - Pulsed	(Note 1)	56	A
V _{GSS}	Gate-Source Voltage		± 30	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	600	mJ
I _{AR}	Avalanche Current	(Note 1)	14	А
E _{AR}	Repetitive Avalanche Energy	(Note 1)	5.5	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	5.5	V/ns
P _D	Power Dissipation (T _C = 25°C)		55	W
	- Derate above 25°C		0.44	W/°C
T _J , T _{STG}	Operating and Storage Temperature Rang	ge	-55 to +150	°C
TL	Maximum Lead Temperature for Soldering 1/8" from Case for 5 seconds	g,	300	°C

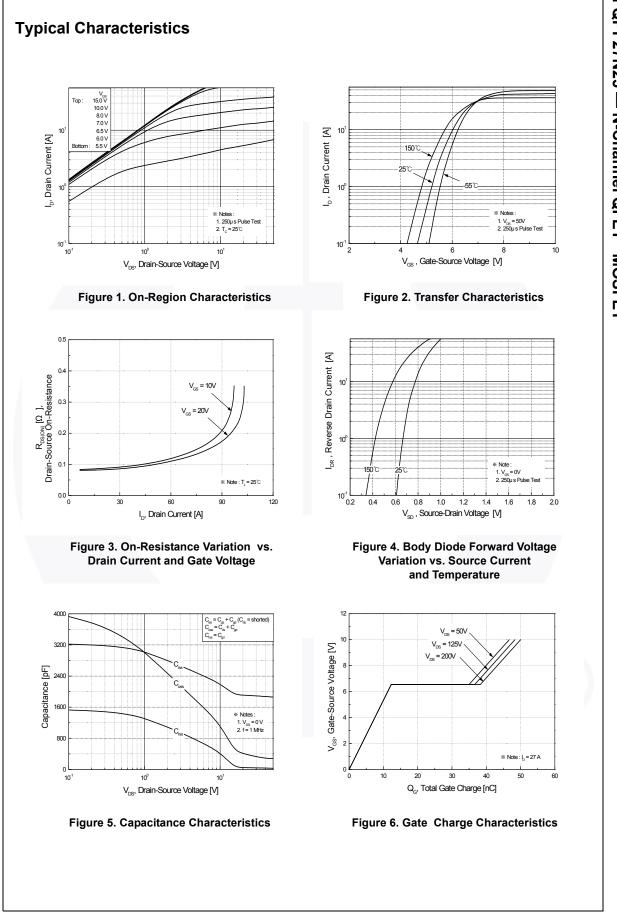
Thermal Characteristics

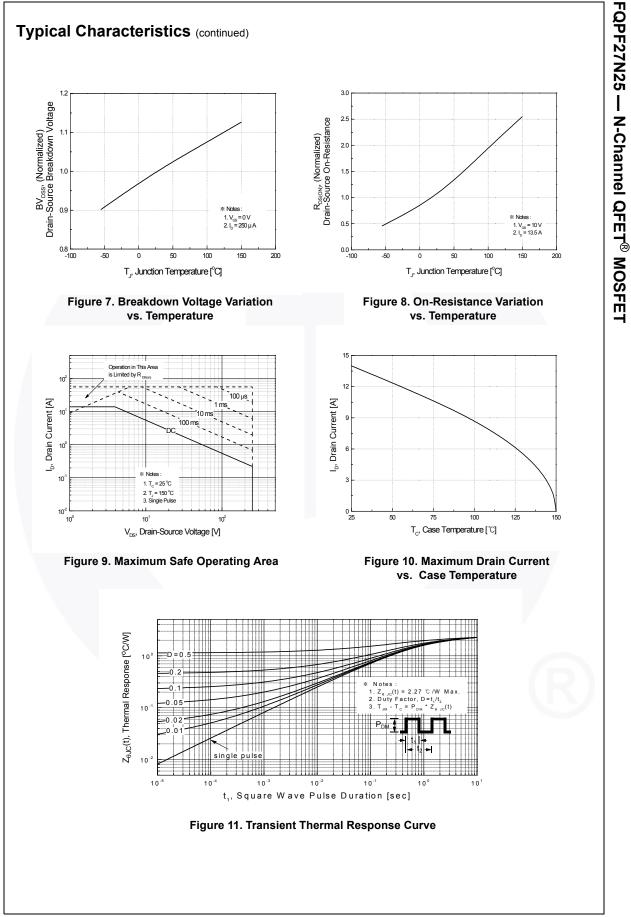
Symbol	Parameter	FQPF27N25	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	2.27	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W

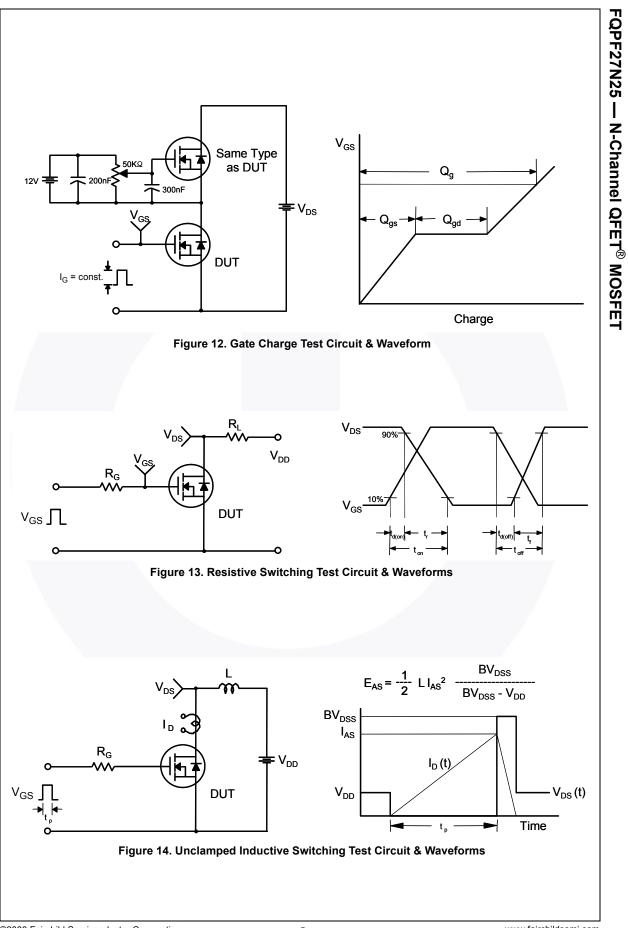
Part NumberTop MarkPackageFQPF27N25FQPF27N25TO-220F		Package	Packing Method	Reel Size	Tape Width		h Q	Quantity	
		Tube N/A		N/A		5	50 units		
lectri	cal C	haracteristics	T _C = 25°C	unless otherwise noted.					
Symbol		Parameter		Test Condit	ons	Min	Тур	Max	Unit
Off Cha	aracto	rietice							
BV _{DSS}	Drain-Source Breakdown Voltage		V _{GS} = 0 V, I _D = 250 μA		250			V	
∆BV _{DSS}						200			v
$/ \Delta T_{J}$	Breakdown Voltage Temperature Coefficient		$I_D = 250 \ \mu A$, Referenced to $25^{\circ}C$			0.29		V/°C	
IDSS	Zero Gate Voltage Drain Current		V _{DS} = 250 V, V _{GS} = 0 V				1	μA	
			V _{DS} = 200 V, T _C = 125°C		1		10	μA	
I _{GSSF}	Gate-	Body Leakage Currer	nt, Forward	V_{GS} = 30 V, V_{DS} = 0	V	-		100	nA
I _{GSSR}	Gate-	Body Leakage Currer	nt, Reverse	V_{GS} = -30 V, V_{DS} = 0	V			-100	nA
On Cha	aractor	vietice							
V _{GS(th)}		Threshold Voltage		V _{DS} = V _{GS} , I _D = 250	μA	3.0		5.0	V
R _{DS(on)}	Static	Drain-Source		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 7.0 \text{ A}$			0.083	0.11	Ω
9 _{FS}		Forward Transconductance $V_{DS} = 50 \text{ V}, \text{ I}_{D} = 7.0 \text{ A}$		A		15		S	
	1	racteristics					1000		_
C _{iss}		Capacitance		V_{DS} = 25 V, V_{GS} = 0	V,		1900	2450	pF
C _{oss}		t Capacitance		f = 1.0 MHz			360	470	pF
C _{rss}	Reverse Transfer Capacitance		nce				45	60	pF
Switch	ing Ch	aracteristics							
t _{d(on)}	Turn-C	On Delay Time		V = 125 V I = 27	٨		32	75	ns
t _r	Turn-C	On Rise Time		V_{DD} = 125 V, I _D = 27 A, R _G = 25 Ω (Note 4)			270	550	ns
t _{d(off)}	Turn-C	Off Delay Time					80	170	ns
t _f	Turn-C	Off Fall Time					120	250	ns
Qg	Total C	Gate Charge		V _{DS} = 200 V, I _D = 27 A, V _{GS} = 10 V			50	65	nC
Q _{gs}	Gate-S	Source Charge					12.5		nC
Q _{gd}	Gate-I	Drain Charge		00	(Note 4)		26		nC
	-			d Maximum Rati	ngs				
I _S		Maximum Continuous Drain-Source Diode Forward Current				14	A		
I _{SM}		um Pulsed Drain-So						56	Α
V _{SD}		Source Diode Forwar	d Voltage	$V_{GS} = 0 \text{ V, } I_S = 14 \text{ A}$ $V_{GS} = 0 \text{ V, } I_S = 27 \text{ A,}$ $dI_F / dt = 100 \text{ A}/\mu\text{s}$				1.5	V
t _{rr}		se Recovery Time					220		ns
Q _{rr}	Reven	se Recovery Charge					1.8		μC

4. Essentially independent of operating temperature.

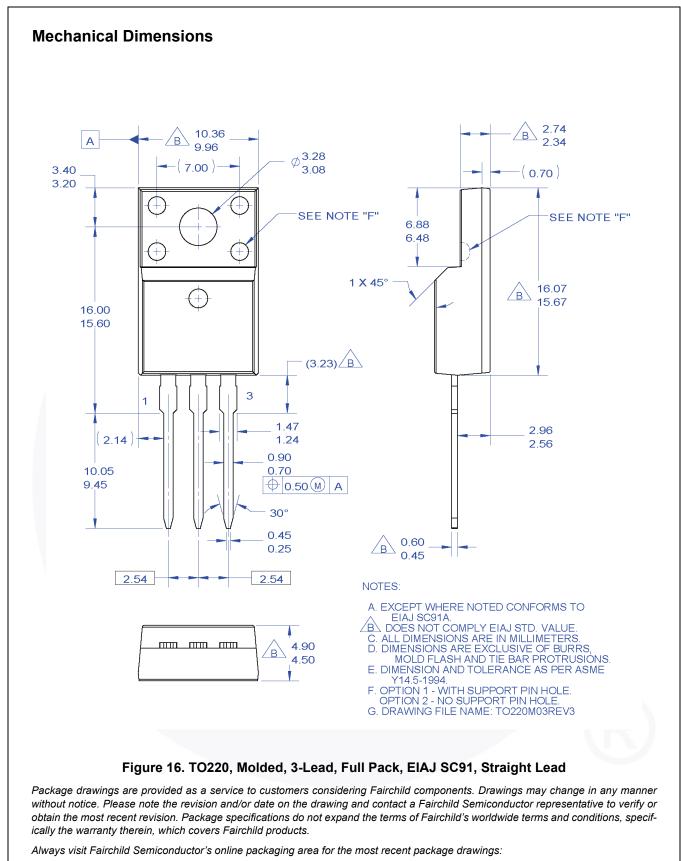
FQPF27N25 — N-Channel QFET[®] MOSFET







DUT + v_{DS} I_{SD} L Driver R_G, Same Type as DUT L F V_{DD} $\prod V_{GS}$ • dv/dt controlled by R_{G} • I_{SD} controlled by pulse period Î Gate Pulse Width V_{GS} D = Gate Pulse Period 10V (Driver) \mathbf{I}_{FM} , Body Diode Forward Current I _{SD} di/dt (DUT) I_{RM} Body Diode Reverse Current V_{DS} (DUT) Body Diode Recovery dv/dt V_{SD} V_{DD} Body Diode Forward Voltage Drop Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



http://www.fairchildsemi.com/package/packageDetails.html?id=PN_TF220-003

FQPF27N25 —

N-Channel QFET[®] MOSFET



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